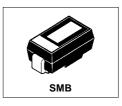
International **ISR** Rectifier

SCHOTTKY RECTIFIER

MBRS130TR

1 Amp



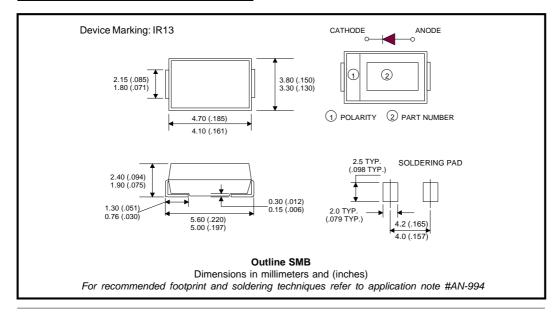
Characteristics	MBRS130TR	Units			
I _{F(AV)} Rectangular waveform	1.0	А			
V _{RRM}	30	V			
I _{FSM} @t _p =5µs sine	230	А			
V _F @ 1.0Apk, T _J = 125°C	0.42	V			
T _J range	- 55 to 125	°C			

Major Ratings and Characteristics

Description/ Features

The MBRS130TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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MBRS130TR

Bulletin PD-20584 rev. D 03/03

Voltage Ratings

Part number	MBRS130TR	
V _R Max. DC Reverse Voltage (V)		
V _{RWM} Max. Working Peak Reverse Voltage (V)	30	

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	1.0	A	50% duty cycle @ T _L =147 °C,	rectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	870	А	5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	Surge Current	50		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	3.0	mJ	$T_{J} = 25 \text{ °C}, I_{AS} = 1A, L = 6mH$	
I _{AR}	Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. Va = 1.5 x Vr typical	

Electrical Specifications

	Parameters	Value	Units		Conditions
V _{EM}	Max. Forward Voltage Drop (1)	0.6	V	@ 1A	T,= 25 °C
		0.67	V	@ 2A	1 _J = 25 C
		0.42	V	@ 1A	T,= 125 °C
		0.52	V	@ 2A	1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1
I _{RM}	Max. Reverse Leakage Current	(1)	0.5	mA	$T_J = 25 \ ^{\circ}C$
		5.0	mA	T _J = 100 °C	$V_R = rated V_R$
		15	mA	T _J = 125 °C	
CT	Max. Junction Capacitance	200	pF	$V_{R} = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C	
Ls	Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs		
	(Rated V _R)				

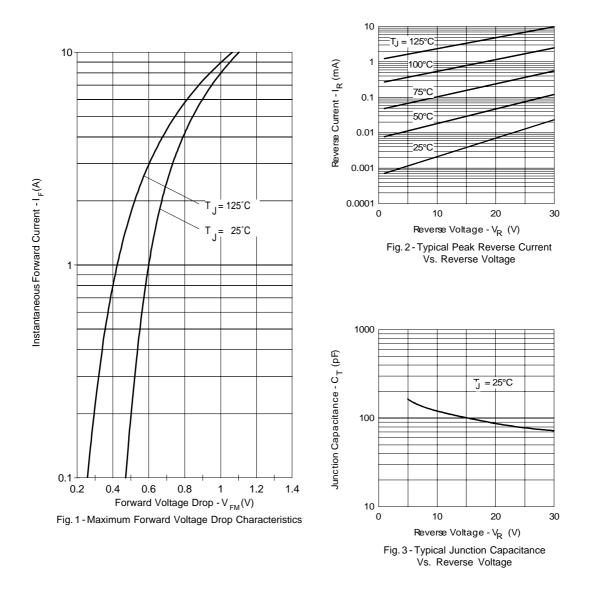
(1) Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	Value	Units	Conditions
TJ	Max. Junction Temperature Range (*)	-55 to 125	°C	
T _{stg}	Max. Storage Temperature Range	-55 to 150	°C	
R _{thJL}	Max.Thermal Resistance Junction to Lead (**)	25	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	DC operation
wt	Approximate Weight	0.10 (0.003)	g (oz.)	
	Case Style	SMB		Similar to DO-214AA
	Device Marking	IR13		

 $\binom{*}{dTj} \ \frac{dPtot}{dTj} < \frac{1}{Rth(j\text{-}a)} \ thermal \ runaway \ condition \ for \ a \ diode \ on \ its \ own \ heatsink$

(**) Mounted 1 inch square PCB



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Bulletin PD-20584 rev. D 03/03

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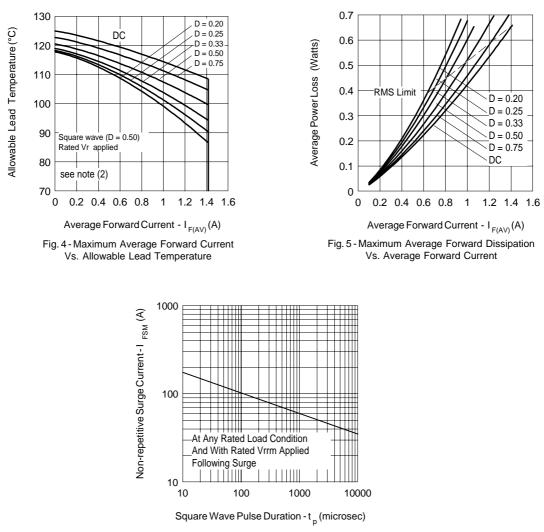
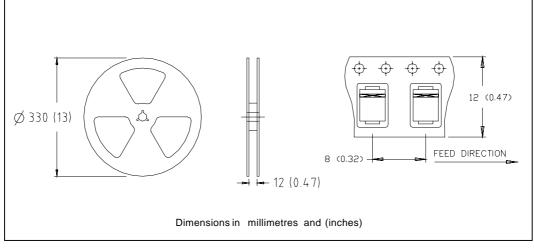


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

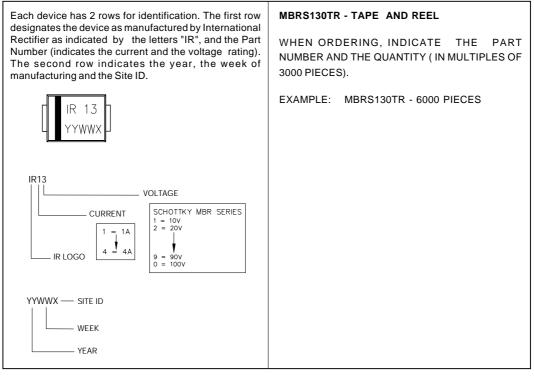
⁽²⁾ Formula used: $T_c = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% rated V_R$

Tape & Reel Information



Marking & Identification

Ordering Information



MBRS130TR

Bulletin PD-20584 rev. D 03/03

International

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level. Qualification Standards can be found on IR's Web site.



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